

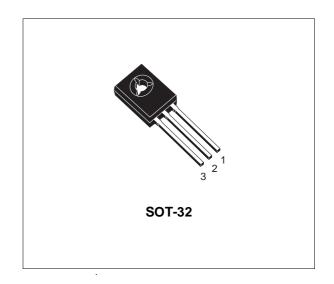
COMPLEMENTARY SILICON POWER TRANSISTORS

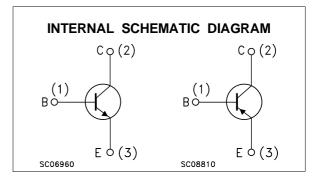
- STMicroelectronics PREFERRED SALESTYPES
- COMPLEMENTARY PNP NPN DEVICES

DESCRIPTION

The BD439 and BD441 are silicon epitaxial-base NPN power transistors in Jedec SOT-32 plastic package, intented for use in power linear and switching applications.

The complementary PNP types are BD440, and BD442 respectively.





ABSOLUTE MAXIMUM RATINGS

| Symbol | Parameter | Value | | | Unit |
|------------------|---|------------|-------|-------|------|
| | | NPN | BD439 | BD441 | |
| | | PNP | BD440 | BD442 | |
| V _{CBO} | Collector-Base Voltage (I _E = 0) | | 60 | 80 | V |
| V_{CES} | Collector-Emitter Voltage (V _{BE} = 0) | | 60 | 80 | V |
| V_{CEO} | Collector-Emitter Voltage (I _B = 0) | | 60 | 80 | V |
| V_{EBO} | Emitter-Base Voltage (I _C = 0) | | | 5 | V |
| Ic | Collector Current | | 4 | 4 | А |
| I _{CM} | Collector Peak Current (t ≤ 10 ms) | | 7 | | А |
| Ι _Β | Base Current | | 1 | | Α |
| P _{tot} | Total Dissipation at T _c ≤ 25 °C | ≤ 25 °C 36 | | 6 | W |
| T _{stg} | Storage Temperature | -65 to 150 | | °C | |
| Tj | Max. Operating Junction Temperature | | 1: | °C | |

For PNP types voltage and current values are negative.

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BD439/BD440/BD441/BD442

THERMAL DATA

| R _{thj-case} | Thermal Resistance Junction-case | Max | 3.5 | °C/W |
|-----------------------|-------------------------------------|-----|-----|------|
| R _{thj-amb} | Thermal Resistance Junction-ambient | Max | 100 | °C/W |

ELECTRICAL CHARACTERISTICS (T_{case} = 25 °C unless otherwise specified)

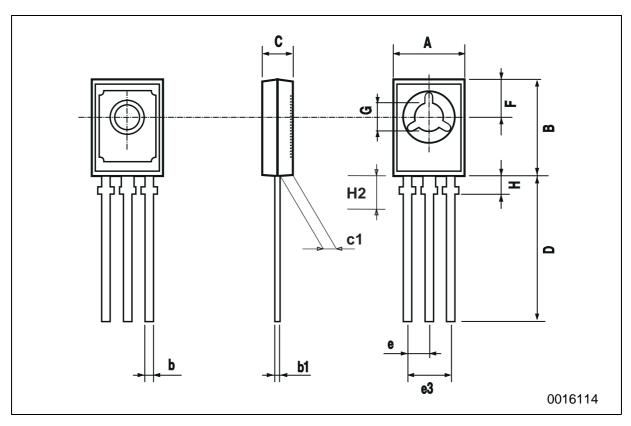
| Symbol | Parameter | neter Test Conditions | | Min. | Тур. | Max. | Unit |
|--------------------------------------|---|--|--|----------------|------------|------------|----------|
| Ісво | Collector Cut-off Current (I _E = 0) | for BD439/440 for BD441/442 | 05 | | | 100 100 | μA μA |
| I _{CES} | Collector Cut-off Current (V _{BE} = 0) | for BD439/440 for BD441/442 | .05 | | | 100 100 | μA μA |
| I _{EBO} | Emitter Cut-off Current (Ic = 0) | V _{EB} = 5 V | | | | 1 | mA |
| V _{CEO(sus)} * | Collector-Emitter Sustaining Voltage (I _B = 0) | I _C = 100 mA | for DB439/440 for BD441/442 | 60 80 | | | V |
| $V_{CE(sat)^*}$ | Collector-Emitter Saturation Voltage | I _C = 2 A | $I_B = 0.2 A$ | | | 0.8 | V |
| V _{BE} * | Base-Emitter Voltage | I _C = 10 mA I _C = 2 A | V _{CE} = 5 V V _{CE} = 1 V | | 0.58 | 1.5 | V |
| h _{FE} * | DC Current Gain | $I_{C} = 10 \text{ mA}$ $I_{C} = 500 \text{ mA}$ | V _{CE} = 5 V for BD439/440 for BD441/442 V _{CE} = 1 V for BD439/440 | 20 15 40 | 130 130 | | |
| | | I _C = 2 A | for BD441/442 V _{CE} = 1 V for BD439/440 for BD441/442 | 40 25 15 | 140 | | |
| h _{FE1} /h _{FE2} * | Matched Pair | I _C = 500 mA | V _{CE} = 1 V | | | 1.4 | |
| f⊤ | Transition frequency | I _C = 250 mA | V _{CE} = 1 V | 3 | | | MHz |

^{*} Pulsed: Pulse duration = 300 ms, duty cycle 1.5 %

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SOT-32 (TO-126) MECHANICAL DATA

| DIM. | mm | | | inch | | | |
|-------|------|------|------|-------|-------|-------|--|
| Diwi. | MIN. | TYP. | MAX. | MIN. | TYP. | MAX. | |
| Α | 7.4 | | 7.8 | 0.291 | | 0.307 | |
| В | 10.5 | | 10.8 | 0.413 | | 0.445 | |
| b | 0.7 | | 0.9 | 0.028 | | 0.035 | |
| b1 | 0.49 | | 0.75 | 0.019 | | 0.030 | |
| С | 2.4 | | 2.7 | 0.040 | | 0.106 | |
| c1 | 1.0 | | 1.3 | 0.039 | | 0.050 | |
| D | 15.4 | | 16.0 | 0.606 | | 0.629 | |
| е | | 2.2 | | | 0.087 | | |
| e3 | 4.15 | | 4.65 | 0.163 | | 0.183 | |
| F | | 3.8 | | | 0.150 | | |
| G | 3 | | 3.2 | 0.118 | | 0.126 | |
| Н | | | 2.54 | | | 0.100 | |



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